

Electronic structure of a newly discovered, optimally doped superconductor

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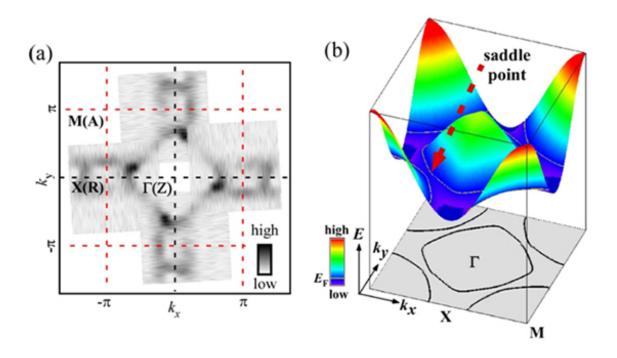


Figure caption: (a) Experimentally determined Fermi surface (black part) and (b) schematic view of the overall band structure of La(O,F)BiS₂ predicted by first principles calculations.

The newly-discovered layered superconductor, Ln(O,F)BiS₂, discovered in 2012, achieves a maximum Tc of 10.6 K. The superconductivity emerges by carrier doping to the parent compound.



There have been no reports on the direct observation of the electronic structure of $Ln(O,F)BiS_2$ in the optimal doping range, which is an important factor to consider in a discussion of the superconducting mechanism.

Now, Kensei Terashima and colleagues at Okayama University have clarified the electronic structure of nearly optimal doped La(O,F)BiS₂.

The team grew single crystal samples by a flux method. They then performed photoemission experiments at BL-28A of Photon Factory and BL25SU of SPring-8.

The Fermi surface topology of optimally doped BiS₂ is about to change due to the presence of van Hove singularity (saddle point) in its <u>electronic structure</u>, which agrees well with the prediction by first principles calculations which take the <u>spin-orbit coupling</u> into account.

The optimal Tc could be realized by EF-crossing of the van Hove singularity in the density of states. On the other hand, despite its higher DOS, Tc of optimally-doped La(O,F)BiS₂ is lower than that of the related compound, under-doped Nd(O,F)BiS₂. Thus there are probably other factors also enhancing Tc in this system, which will need to be clarified by further study.

More information: "Proximity to Fermi-surface topological change in superconducting LaO_{0.54}F_{0.46}BiS₂." *Phys. Rev. B* 90, 220512(R) – Published 22 December 2014. <u>journals.aps.org/prb/abstract/...</u>
3/PhysRevB.90.220512

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